

SWITCHING REGULATOR APPLICATIONS

Features

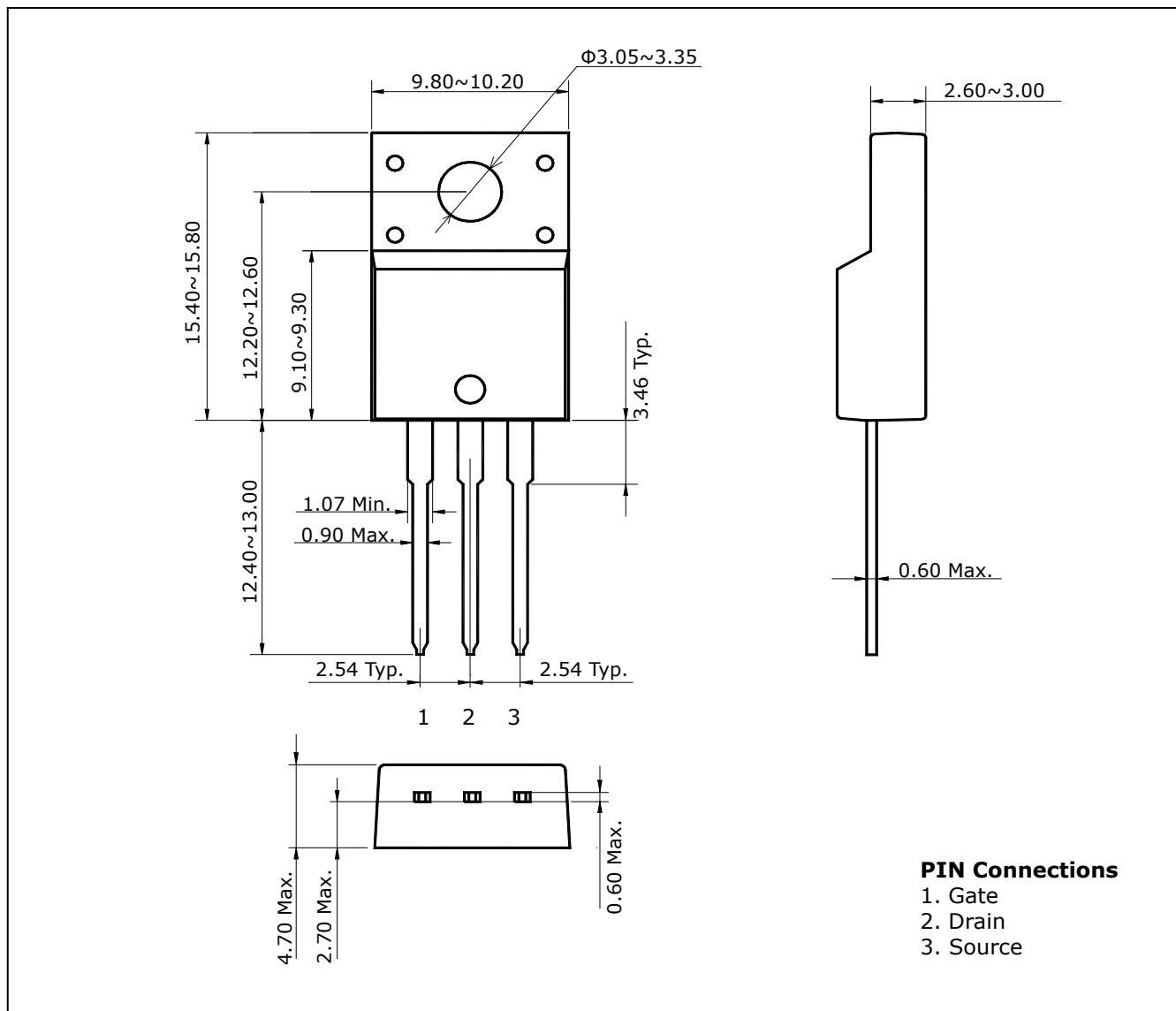
- High Voltage: $BV_{DSS}=600V(\text{Min.})$
- Low C_{rSS} : $C_{rSS}=12pF(\text{Typ.})$
- Low gate charge : $Q_g=28nC(\text{Typ.})$
- Low $R_{DS(on)}$: $R_{DS(on)}=1.2\Omega(\text{Max.})$

Ordering Information

Type NO.	Marking	Package Code
STK0760F	STK0760	TO-220F-3L

Outline Dimensions

unit : mm



Absolute maximum ratings

(Tc=25°C)

Characteristic	Symbol	Rating	Unit	
Drain-source voltage	V_{DSS}	600	V	
Gate-source voltage	V_{GSS}	±30	V	
Drain current (DC)	I_D	(Tc=25°C)	7	A
		(Tc=100°C)	3.2	A
Drain current (Pulsed) *	I_{DM}	28	A	
Drain power dissipation	P_D	30	W	
Avalanche current (Single) ②	I_{AS}	7	A	
Single pulsed avalanche energy ②	E_{AS}	230	mJ	
Avalanche current (Repetitive) ①	I_{AR}	7	A	
Repetitive avalanche energy ①	E_{AR}	7.5	mJ	
Junction temperature	T_J	150	°C	
Storage temperature range	T_{stg}	-55~150		

* Limited by maximum junction temperature

Characteristic		Symbol	Typ.	Max	Unit
Thermal resistance	Junction-case	$R_{th(J-C)}$	-	4.16	°C/W
	Junction-ambient	$R_{th(J-a)}$	-	62.5	

Electrical Characteristics

(Tc=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit	
Drain-source breakdown voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0$	600	-	-	V	
Gate threshold voltage	$V_{GS(th)}$	$I_D=250\mu A, V_{DS}=V_{GS}$	2.0	-	4.0	V	
Drain-source cut-off current	I_{DSS}	$V_{DS}=600V, V_{GS}=0V$	-	-	1	μA	
Gate leakage current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 30V$	-	-	± 100	nA	
Drain-source on-resistance ④	$R_{DS(on)}$	$V_{GS}=10V, I_D=3.5A$	-	1.0	1.2	Ω	
Forward transfer conductance ④	g_{fs}	$V_{DS}=10V, I_D=3.5A$	-	7.3	-	S	
Input capacitance	C_{iss}	$V_{GS}=0V, V_{DS}=25V, f=1MHz$	-	950	1430	pF	
Output capacitance	C_{oss}		-	85	130		
Reverse transfer capacitance	C_{rss}		-	12	18		
Turn-on delay time	$t_{d(on)}$	$V_{DD}=300V, I_D=7A, R_G=25\Omega$	-	16	-	ns	
Rise time	t_r		-	60	-		
Turn-off delay time	$t_{d(off)}$		③④	-	80		-
Fall time	t_f		-	65	-		
Total gate charge	Q_g	$V_{DS}=300V, V_{GS}=10V, I_D=7A$	-	28	42	nC	
Gate-source charge	Q_{gs}		-	5.5	8.3		
Gate-drain charge	Q_{gd}		③④	-	11		17

Source-Drain Diode Ratings and Characteristics

(Tc=25°C)

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Source current	I_S	Integral reverse diode in the MOSFET	-	-	7	A
Source current (Pulsed) ①	I_{SM}		-	-	28	
Forward voltage ④	V_{SD}	$V_{GS}=0V, I_S=7A$	-	-	1.4	V
Reverse recovery time	t_{rr}	$I_S=7A, V_{GS}=0, di_s/dt=100A/us$	-	365	-	ns
Reverse recovery charge	Q_{rr}		-	4.23	-	μC

Note ;

- ① Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- ② $L=9.8mH, I_{AS}=7A, V_{DD}=50V, R_G=27\Omega$
- ③ Pulse Test : Pulse Width < 300us, Duty cycle $\leq 2\%$
- ④ Essentially independent of operating temperature

Electrical Characteristic Curves

Fig. 1 $I_D - V_{DS}$

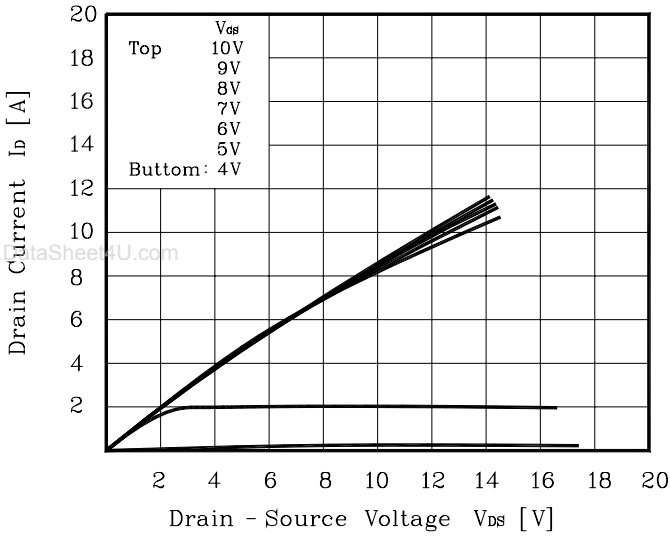


Fig. 2 $I_D - V_{GS}$

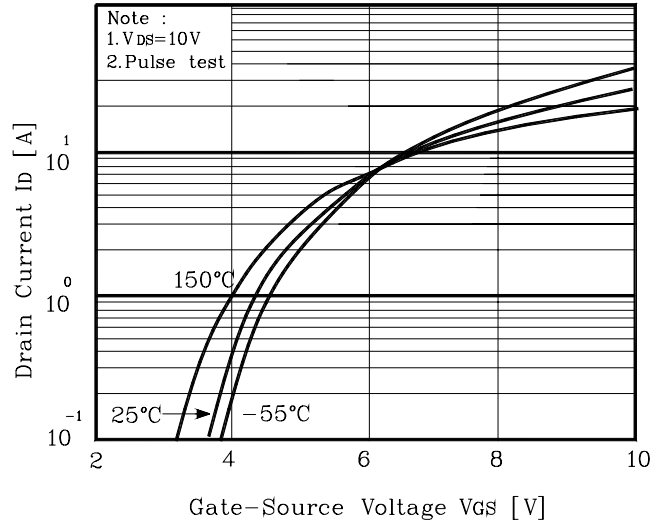


Fig. 3 $R_{DS(on)} - I_D$

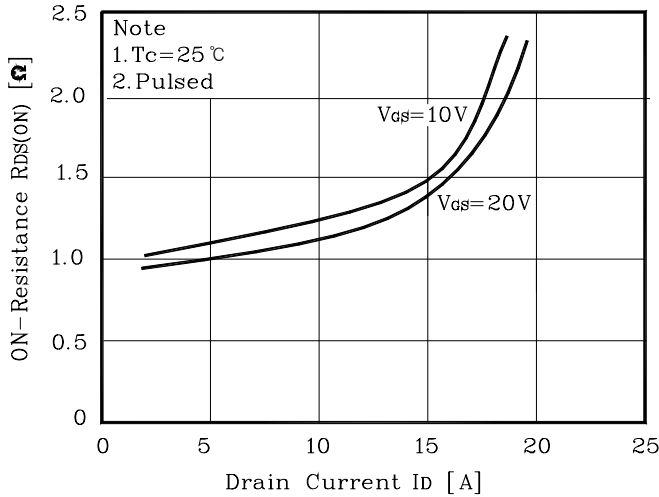


Fig. 4 $I_S - V_{SD}$

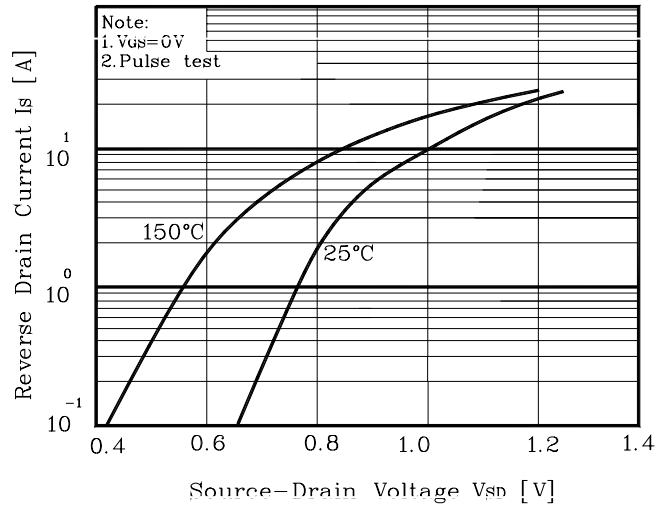


Fig. 5 Capacitance - V_{DS}

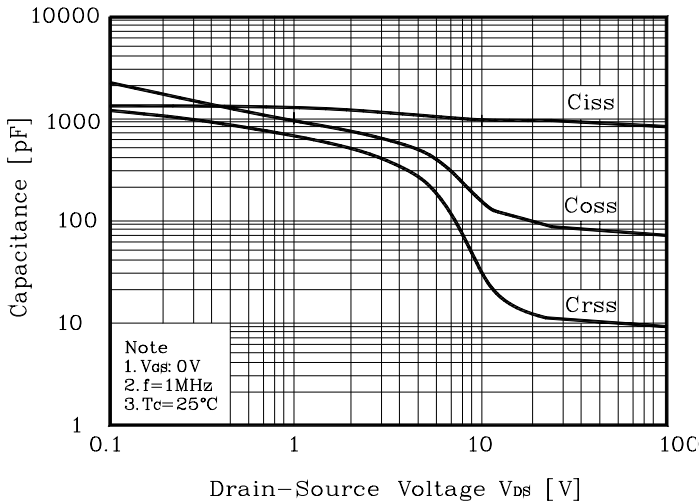


Fig. 6 $V_{GS} - Q_G$

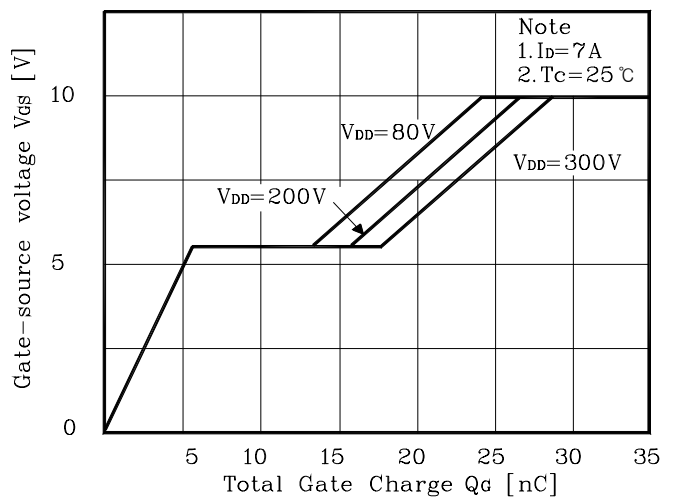


Fig. 7 $V_{DS} - T_J$

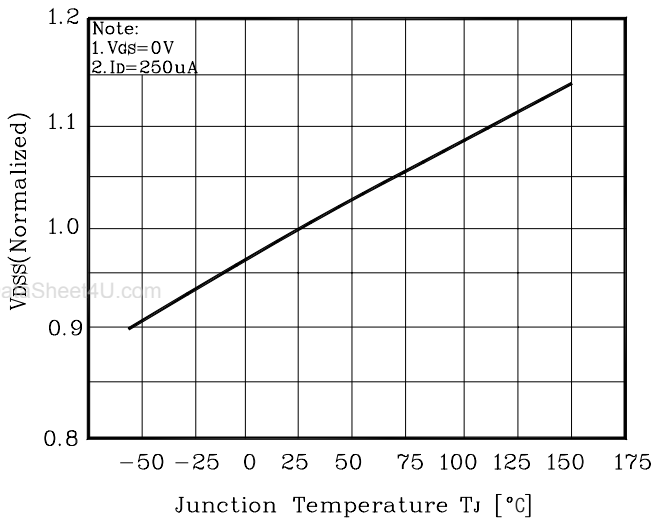


Fig. 8 $R_{DS(on)} - T_J$

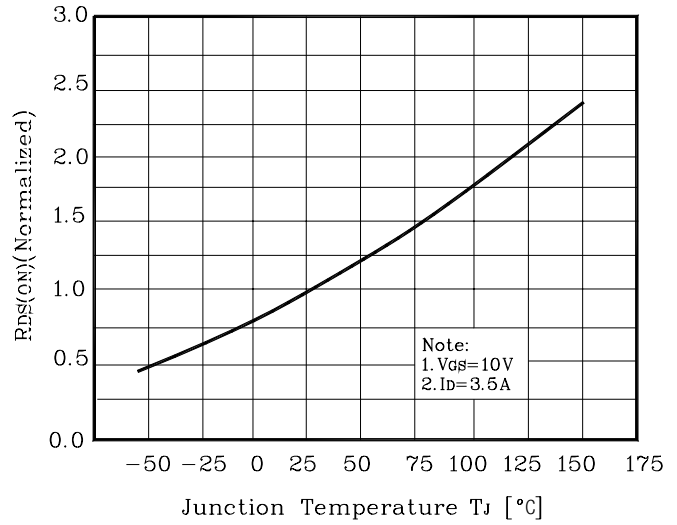


Fig. 9 $I_D - T_C$

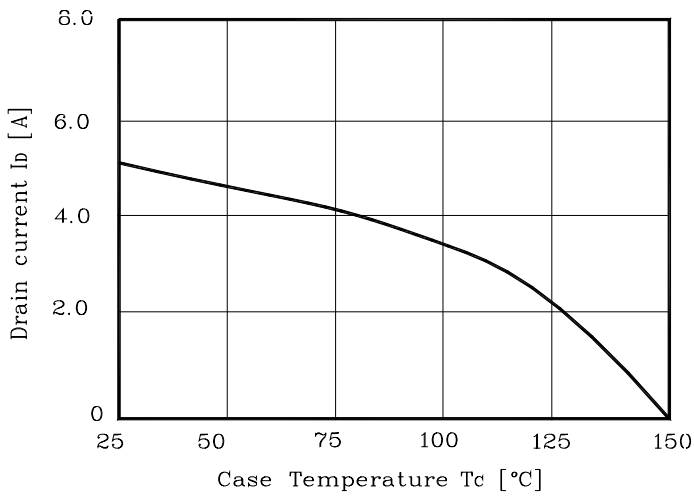


Fig. 10 Safe Operating Area

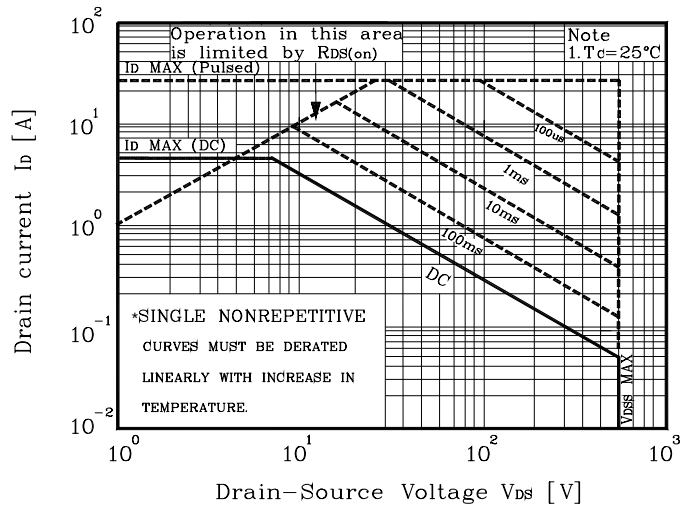


Fig. 11 Gate Charge Test Circuit & Waveform

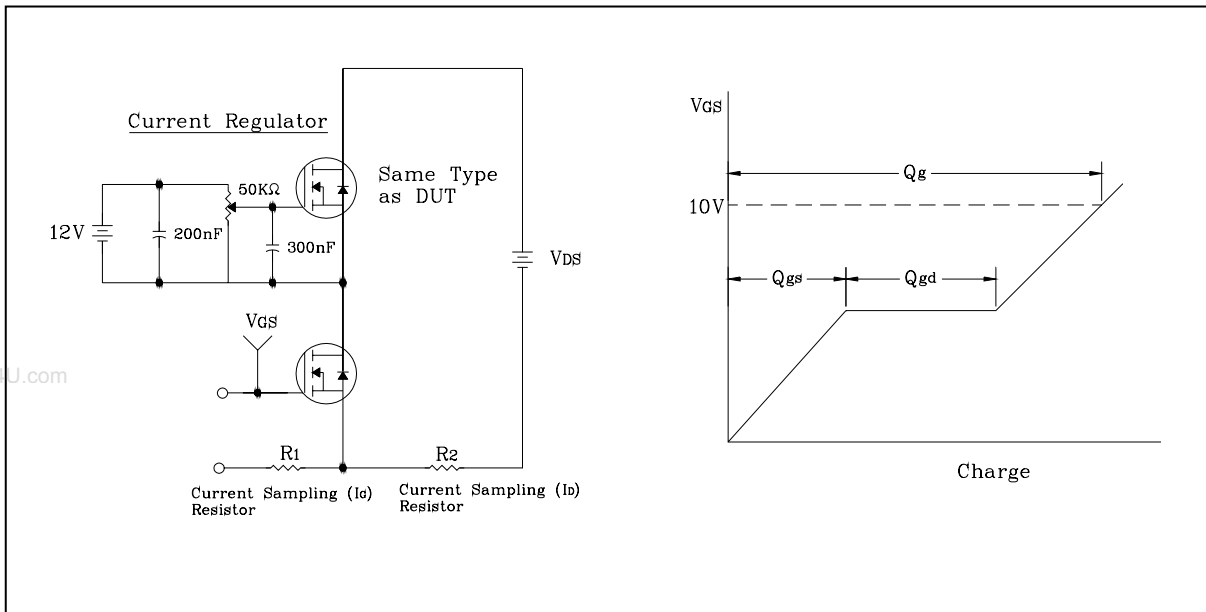


Fig. 12 Resistive Switching Test Circuit & Waveform

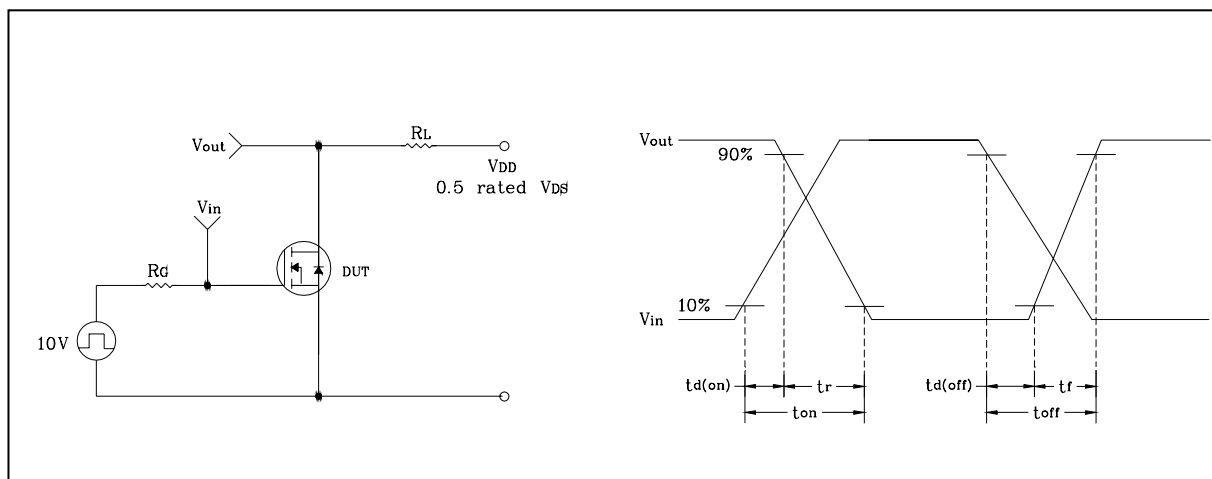
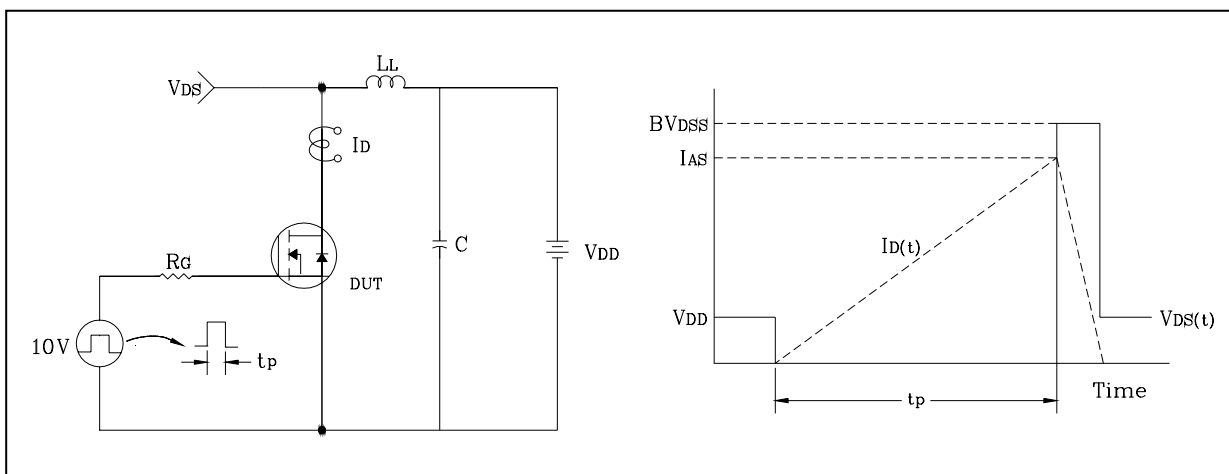


Fig. 13 E_{AS} Test Circuit & Waveform



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